DS - 08/27/22/2ECTRONIC INFORMATION DISCLOSURE STATEMENT

Electronic Version v18

Stylesheet Version v18.0

Title of Invention

MOS VARACTOR USING ISOLATION WELL

Application Number:

10/711,144

Confirmation Number:

First Named Applicant:

Douglas Coolbaugh

Attorney Docket Number:

BUR920040107US1

Art Unit:

2823

Examiner:

Khiem D. Nguyen

Search string:

(6407412 or 6521506 or 6521939 or 6542043 or 6566971 or 6670654 or 6686640

or 20030136992 or 20020074589).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
KN	1	6407412	2002-06-18	Iniewski et al			
	2	6521506	2003-02-18	Coolbaugh et al			
П	3	6521939	2003-02-18	Yeo et al			
П	4	6542043	2003-04-01	Cao		X	
	5	6566971	2003-05-20	Gutierrez			
$ \mathbf{V} $	6	6670654	2003-12-30	Lanzerotti et al			
KN	7	6686640	2004-02-03	Mheen et al			

US Published Applications

Note: Applicant is not required to submit a paper copy of cited US Published Applications

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
KN	1	20030136992	2003-07-24	Adan			
KN	2	20020074589	2002-06-20	Benaissa et al			

Signature

Examiner Name	Date	
/Khiem Nguyen/	08/06/2006	

Form PTO-1449 U.S. DEPARTMENT OF COMMERCE (REV. 7-80)PATENT AND TRADEMARK OFFICE Serial No. Atty. Docket No. BUR920040107U\$1 (17619) 10/711144 LIST OF PRIOR ART Applicant CITED BY APPLICANT Douglas D. Coolbaugh, et al. (Use several sheets if necessary) Group Filing Date 2823 8/27/04 Unassigned **U.S. PATENT DOCUMENTS** EXAMINER DOCUMENT NUMBER DATE CLASS SUBCLASS NAME FILING DATE INITIAL* (if appropriate) AA AB FOREIGN PATENT DOCUMENTS DOCUMENT NUMBER DATE COUNTRY CLASS **SUBCLASS** TRANSLATION YES NO KN EP0902483 A1 3/17/1999 **EPO** WO 03/043079 A1 5/22/2003 **PCT** KN OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.) Joachim N. Burghartz, et al., "Integrated RF and Microwave Components in BiCMOS KN Technology", IEEE Transactions On Electron Devices, Vol. 43, No. 9, September 1996 (pp. 1559-1570); and R.A. Moline, et al., "Ion-Implanted Hyperabrupt Junction Voltage Variable Capacitors", IEEE KN Transactions On Electron Devices, Vol. ED-19, No. 2, February 1972 (pp. 267-273). **EXAMINER** /Khiem Nguyen/ DATE CONSIDERED 08/06/2006 * EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.